

Research Article

The Effect of Alumina and Magnesia Supported Germanium Nanoparticles on the Growth of Carbon Nanotubes in the Chemical Vapor Deposition Method

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The effect of alumina and magnesia supported germanium (Ge) nanoparticles on the synthesis of carbon nanotubes (CNTs) using the chemical vapor deposition (CVD) method in atmospheric pressure was investigated. The TEM micrographs confirmed the formation of carbon nanotubes, and the field emission scanning electron microscopy (FESEM) analysis suggested a tip-growth mechanism for the grown carbon nanotubes. The X-ray diffraction (XRD) pattern indicated a graphitic nature of the carbon nanotubes. The obtained CNTs using Ge nanoparticles supported by MgO resulted in a higher degree of graphitization than the CNTs obtained using Ge nanoparticles supported by Al₂O₃. Raman spectroscopy analysis of the CNTs confirmed the presence of radial breathing modes (RBM), which verified the formation of CNTs. High frequency Raman analysis demonstrated that the degree of graphitization of the synthesized CNTs using magnesia supported Ge nanoparticles is higher than that of the alumina supported Ge nanoparticles with the values of (I_D/I_G) ratios equal to 0.45 and 0.73, respectively.

1. Introduction

Carbon nanotubes (CNTs) have attracted attention in the last decade because of their mechanical, electrical, thermal, and chemical properties. Prominent properties of CNTs, including their strength and elasticity reported with Young's module value of up to 2 TPa [1], the high aspect ratios of CNTs (1000 : 1), and their exceptional electrical conductivity at much lower loading when compared with stainless steel, have attracted a great deal of interest [2]. CNTs' superior field emission properties, because of their emission at low voltages, make them preferred over conventional electron sources [3]. Moreover, CNTs have been used for hydrogen storage [4].

Numerous methods have been employed to synthesize CNTs, including plasma based arc discharge and laser ablation in addition to the thermal methods, such as chemical vapor deposition (CVD), plasma enhanced chemical vapor deposition (PECVD), alcohol catalytic CVD (ACCVD),

hydrothermal or sonochemical process, and high-pressure CO conversion (HiPCo) [5]. Nevertheless, the CVD method has significant advantages over the other methods. The CVD method is widely used for carbon nanotube synthesis because of its high production yield and scale-up capability [6].

In the CVD method, a catalyst is usually used to help growing carbon nanotubes. These catalysts are mostly transition metals such as Ni, Fe, and Co [7]. In addition to transition metals, semiconductor nanoparticles such as SiC, Si, and Ge have also been shown to be effective in the synthesis of carbon nanotubes because of their capability to dissolve carbon effectively for the CNT growth [8]. The catalytic decomposition of the carbon precursor molecules on the surface of the metal catalyst particles is followed by the diffusion of the released carbon atoms into the metal particles. Carbon saturation in the metal occurs either by reaching the carbon solubility limit in the metal at a given temperature or by lowering the solubility limit via

a temperature decrease. Super saturation results in the solid carbon precipitation over the metal particles. However, the success of semiconductors in the CNT production suggests that only nanoscale curvatures would be enough to obtain CNTs in the presence of a carbon source. Therefore, in this study, Ge nanoparticles were used to produce CNTs.

The physical shape of the precipitated carbon depends on several parameters including the catalyst/semiconductor nanoparticle and its size [9], the use of support [10], and the precipitation rate [11]. The use of support is one of the key factors in the catalyst/nanoparticle preparation for the CVD process. In the synthesis of CNTs, the same catalyst can act differently in the presence of different supports. The commonly used supports in the CVD process are quartz, silica, alumina, zeolite, CaCO_3 , and magnesia [12]. The support material and its morphology and textural properties greatly affect the yield and quality of the resulting CNTs. Accordingly, the effect of magnesia and alumina supports in the presence of Ge nanoparticles in a CVD process on the obtained CNTs has been investigated in this paper.

2. Materials and Methods

For the catalyst synthesis, oleic acid, oleyamine, and methanol were stirred in a 20 mL beaker and mixed well for 4 hours. Then, 0.6 mmol of germanium iodide (GeI_2) and 0.4 mmol of magnesia with molar ratio of 0.6:0.4 were added to the mixture. The reaction temperature was gradually increased from 80°C to 160°C in 4 hours (20 degrees every 1 hour) [13]. It was observed that the yellowish color of the solution changed to a brownish color, indicating that the reaction had taken place. The resulting solution was sealed and transferred to an oven and dried at 100°C . The obtained powder was then washed 3 times with distilled water, centrifuged at 7000 rpm, and calcined at 500°C for 4 hours. In a separate run of the experiment, the same methodology was conducted with the exception of using alumina instead of magnesia in order to investigate the effect of the support.

For the CNT production, 2 g of the obtained catalysts were placed in the CVD reactor and heated in the presence of N_2 to 600°C . The reactor was then purged with H_2 while the temperature was maintained at 600°C for 1 hour. After that, the temperature of the reactor was increased to 1000°C in the presence of N_2 . Once the temperature was stabilized at 1000°C , the methane gas was introduced to the reaction tube with a flow rate of 500 mL/min for 3 hours. The reactor was then cooled down to the ambient temperature while passing N_2 gas for 30 minutes. The obtained powder was collected and purified using 50 mL of concentrated HCl for further characterization. Field emission scanning electron microscopy (FESEM) pictures were obtained to visualize the surface morphology of the produced CNTs, using a Zeiss SUPRA55 scanning electron microscope at an operating voltage of 3 kV. Transmission electron microscopy (TEM) was performed to visualize the nanotubes (Hitachi477700m10 Kv). Energy-dispersive X-ray spectroscopy (EDX) (Zeiss SUPRA55) was used to investigate the weight percentages of the present elements in the synthesized powder. Raman spectrophotometer,

TABLE 1: Weight percentages of different components present in the obtained Ge-MgO-CNT and Ge- Al_2O_3 -CNT.

Element	Ge-MgO-CNT		Ge- Al_2O_3 -cnt	
	Weight %	Atomic %	Weight %	Atomic %
C	74.01	80.26	54.57	64.78
O	16.88	14.50	24.90	22.99
Mg	5.11	2.74	—	—
Al	—	—	17.28	10.13
Ge	4	2.50	3.25	2.10
Total	100.00		100.00	

with a laser source operating at the wavelength of 514 nm (Horiba Jobin Yvon, LabRam HR800), was used to confirm the formation of CNTs.

3. Result and Discussion

FESEM was employed for the analysis of the morphology and density of the obtained CNTs. The FESEM pictures of the catalysts before the experiment are shown in Figures 1(a) and 1(b) for the Ge/MgO and Ge/ Al_2O_3 supported catalysts, respectively. These pictures show the flower-like morphology and high surface area of the catalysts. The SEM images, which show the CNT growth in the presence of Ge/MgO and Ge/ Al_2O_3 catalysts, are presented in Figures 1(c), 1(d), 1(e), and 1(f). The high aspect ratio nanostructures of the CNTs are observed in these pictures. The nanotubes were grown on the surface of the Ge nanoparticles. This suggests that the tip-growth mechanism is likely to be the possible mechanism for the CNT synthesis under the present conditions [14]. The area density of the deposited CNTs appeared to be high, and the CNTs structures had randomly oriented spaghetti-like morphology in both cases after the purification (see Figures 1(g) and 1(h)).

The TEM micrographs of the obtained CNTs after purification confirmed the formation of the nanotubes. The diameter and the morphology of the obtained CNTs can also be investigated using the TEM pictures (Figure 2). The carbon nanotubes are distinguished in Figure 2 by their hollow compartments with average diameters of 16.1 nm and 21.4 nm for Ge/MgO-CNTs and Ge/ Al_2O_3 -CNTs, respectively.

The EDX spectrum obtained from GeMgO-CNT and Ge Al_2O_3 -CNT samples are shown in Figures 3(a) and 3(b). As can be observed in Table 1, the weight percentage of carbon in the obtained CNTs when MgO supported Ge is used is higher (74.01%) than that of the Al_2O_3 supported Ge (54.57%).

XRD analysis was carried out to examine the crystalline structure of the CNTs, and the spectra of Ge/MgO-CNT and Ge/ Al_2O_3 -CNT are presented in Figures 4(a) and 4(b), respectively. The peak at $2\theta = 26^\circ$ is attributed to the graphitic peak confirming the presence of carbon nanotubes in the sample. For Ge/MgO-CNT, the peak at $2\theta = 44^\circ$ is attributed to the (101) plane of the nanotube, and the peak at $2\theta = 43^\circ$ is assigned to the CNTs obtained from Ge/ Al_2O_3 . The intensity of the main CNT peak (002) is lower when Ge

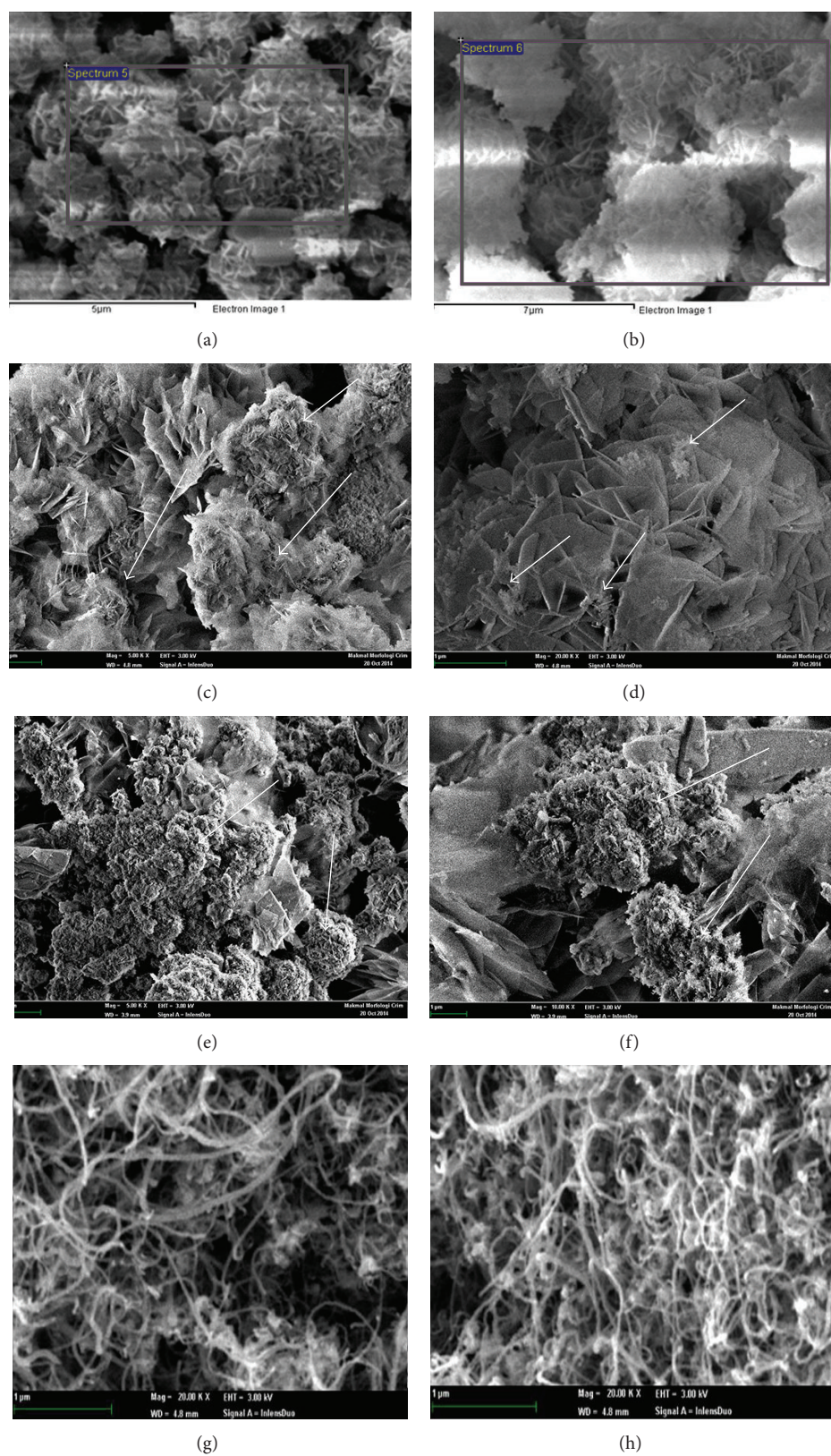


FIGURE 1: SEM images of (a) Ge/MgO, (b) Ge/Al₂O₃, ((c), (d)) Ge/MgO-CNT, ((e), (f)) Ge/Al₂O₃-CNT, (g) CNTs obtained from Ge/MgO, and (h) CNTs obtained from Ge/Al₂O₃.

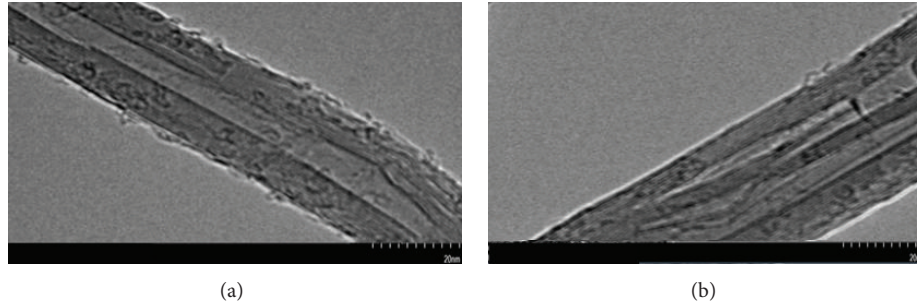


FIGURE 2: TEM images of CNTs obtained using (a) Ge/MgO and (b) Ge/Al₂O₃.

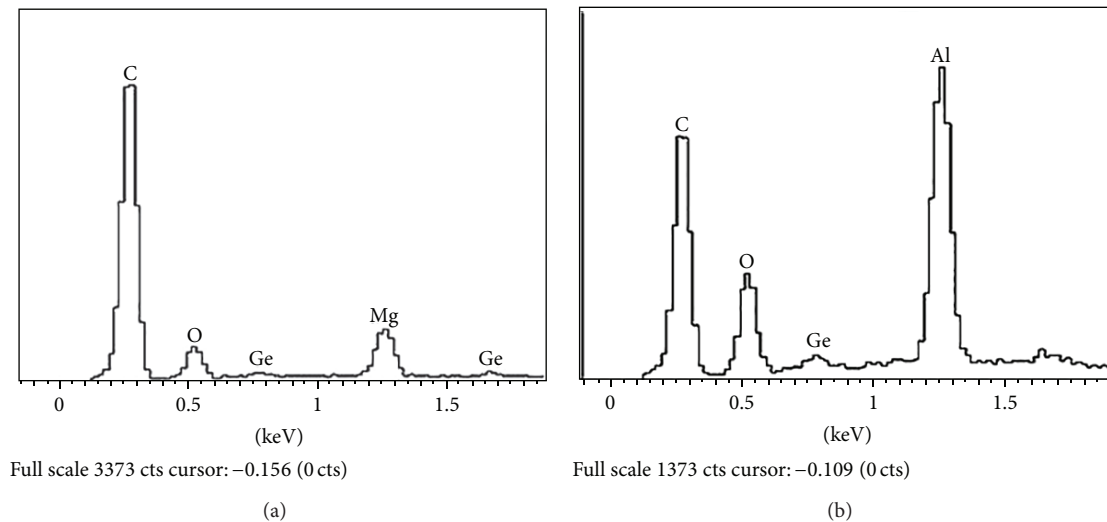


FIGURE 3: EDX spectrum of (a) Ge/MgO-CNT and (b) Ge/Al₂O₃-CNT.

is supported by Al₂O₃, which may be the reason for the absence of the (101) peak and, instead, the presence of (100) in its diffraction pattern [15]. The broader full width at half maximum (FWHM) of the (002) peak of Ge/MgO-CNT indicates a lower crystallinity in comparison with Ge/Al₂O₃-CNT. The peaks attributed to the presence of MgO, Al₂O₃, and Ge are shown in Figures 4(a) and 4(b).

Raman spectroscopy determines the details of the quality and structure of the produced carbon nanotubes. Figure 5 shows the Raman spectra of the carbon nanotubes at room temperature. The presented spectra are divided into two main zones: the low frequency in the 150–400 cm⁻¹ region (shown as an insert in Figure 4) and the high frequency zone of 0–3000 cm⁻¹.

Evidence for the presence of Radial Breathing Mode (RBM) vibrations in Ge/MgO-CNT and Ge/Al₂O₃-CNT samples is obtained from the low wave number range of the spectra (insert of Figure 4). The presence of RBM is indicative of the presence of CNTs. Since RBM is not present in the graphite, this range of frequency can be investigated to confirm the CNTs formation. In the RBM, all of the carbon atoms move in the radial direction and generate a breathing-like vibration [16]. The peaks located at 180 cm⁻¹ and 270 cm⁻¹ in the Raman spectra of Ge/MgO-CNT are due

to the RBM of CNTs. The RBM vibrations for Ge/Al₂O₃-CNT are located at 190 cm⁻¹ and 290 cm⁻¹ [16]. The observation of the RBM in the Raman spectra of the prepared CNTs samples is indicative of the high purity of the samples, specifically for Ge/MgO-CNT with lower RBM (180, 270 cm⁻¹) than Ge/Al₂O₃-CNT (190 and 290 cm⁻¹) [17].

Two main peaks observed in the high frequency zone of the obtained Raman spectra are the D and G bands. The G-band is attributed to the stretching mode of the C–C bond in the graphite plane and demonstrates the presence of crystalline graphitic carbon. For both Ge/MgO-CNT and Ge/Al₂O₃-CNT, the G band appears at 1560 cm⁻¹. The D-band, centered around 1350 cm⁻¹, originates from the disorder in the sp²-hybridised carbon and is an indication of the presence of lattice defects in the graphite sheet that make up the CNT layers. The I_D/I_G intensity ratio is reported to increase with an increase in the structural disorder of the CNTs. Lower I_D/I_G values are representative of well-graphitized CNTs. The values of (I_D/I_G) for the CNTs grown using Ge/MgO and Ge/Al₂O₃ nanoparticles are calculated to be 0.45 and 0.73, respectively. The I_D/I_G values confirm that the degree of long-range ordered crystalline perfection of CNTs grown using MgO as support is higher than that of the CNTs grown using Al₂O₃ as support. These results

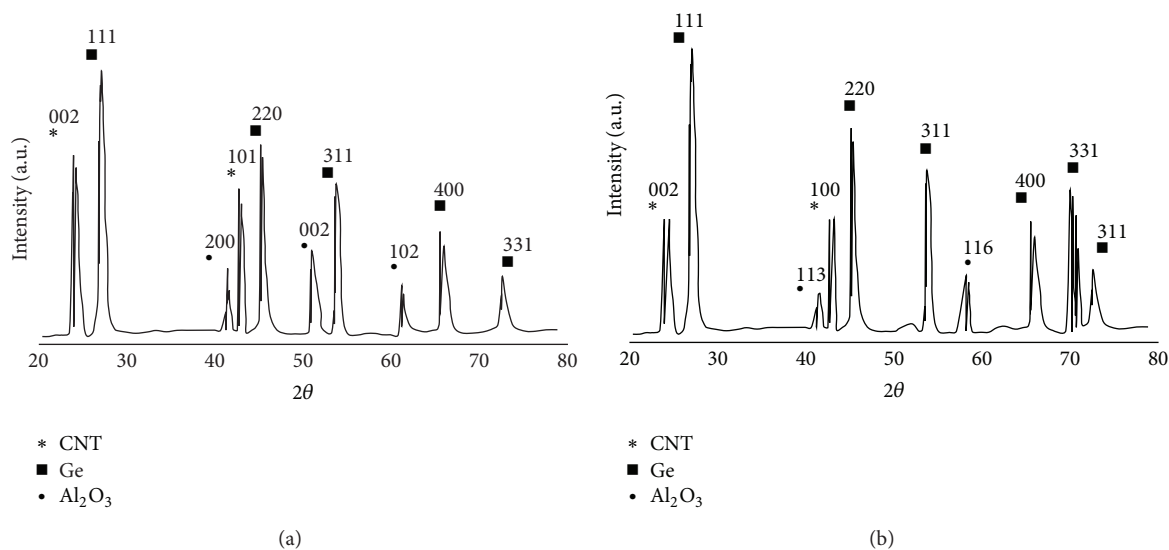


FIGURE 4: XRD spectra of (a) Ge/MgO-CNT and (b) Ge/Al₂O₃-CNT. Ge/MgO-CNT exhibits a lower crystallinity in comparison with Ge/Al₂O₃-CNT.

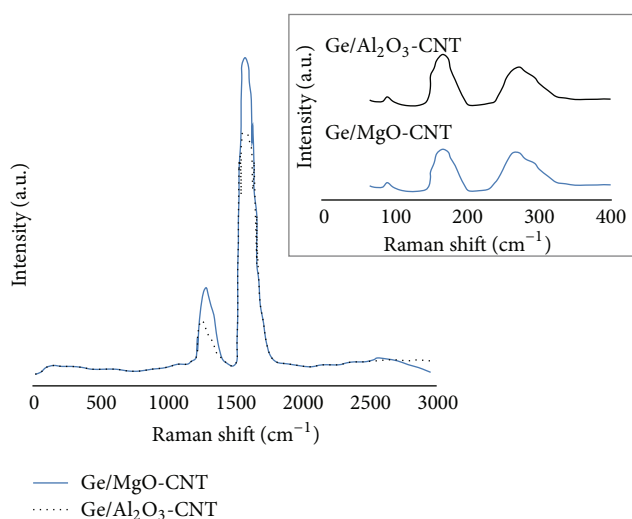


FIGURE 5: High frequency Raman spectrum of Ge/MgO-CNT and Ge/Al₂O₃-CNT, (insert) Low frequency Raman spectrum of Ge/MgO-CNTs and Ge/Al₂O₃-CNTs.

are consistent with the XRD results. Therefore, it can be concluded that the degree of graphitization of the CNTs is affected by using different supports for the catalysts.

4. Conclusion

Carbon nanotubes have been synthesized successfully by the decomposition of methane in the CVD process, and the effect of two different supports for the Ge nanoparticles on the CNT growth has been investigated. This study reveals that the use of different supports strongly affects not only the crystallinity but also the yield, morphology, and microstructure of the catalyst. The XRD and Raman spectroscopy of the CNTs

grown over the Ge nanoparticles supported by MgO resulted in a higher degree of graphitization when compared to that of the Ge nanoparticles supported by Al₂O₃. The Raman spectra of Ge/MgO-CNT and Ge/Al₂O₃-CNT were used to calculate the values of the (I_D/I_G) ratios equal to 0.45 and 0.73, respectively. The tip-growth mechanism, which signals the use of supports, was observed in the SEM results. The TEM micrographs confirmed the formation of carbon nanotubes with small average diameters equal to 16.1 nm and 21.4 nm for Ge/MgO-CNTs and Ge/Al₂O₃-CNTs, respectively. Evidence of the presence of RBM in the spaghetti-like metal-filled tubes was obtained from the low frequency Raman spectrum analysis. It was concluded that MgO supported Ge will result in CNTs with superior properties than the Al₂O₃ supported Ge.

Conflict of Interests

The authors declare no conflict of interests.

Acknowledgments

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